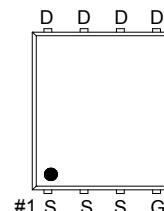
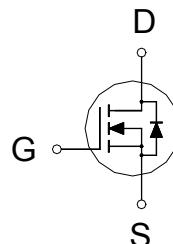


**NIKO-SEM**
**N-Channel Enhancement Mode  
Field Effect Transistor**
**PK504BA  
PDFN 5x6P  
Halogen-Free & Lead-Free**
**PRODUCT SUMMARY**

$V_{(BR)DSS}$	$R_{DS(ON)}$	$I_D$
30V	9mΩ	43A


G. GATE  
D. DRAIN  
S. SOURCE
**ABSOLUTE MAXIMUM RATINGS ( $T_A = 25^\circ\text{C}$  Unless Otherwise Noted)**

PARAMETERS/TEST CONDITIONS		SYMBOL	LIMITS	UNITS
Drain-Source Voltage		$V_{DS}$	30	V
Gate-Source Voltage		$V_{GS}$	$\pm 20$	V
Continuous Drain Current	$T_C = 25^\circ\text{C}$	$I_D$	43	A
	$T_C = 100^\circ\text{C}$		27	
Pulsed Drain Current <sup>1</sup>		$I_{DM}$	120	
Continuous Drain Current	$T_A = 25^\circ\text{C}$	$I_D$	11	A
	$T_A = 70^\circ\text{C}$		9.3	
Avalanche Current		$I_{AS}$	27	
Avalanche Energy	$L = 0.1\text{mH}$	$E_{AS}$	36	mJ
Power Dissipation	$T_C = 25^\circ\text{C}$	$P_D$	31	W
	$T_C = 100^\circ\text{C}$		20	
Power Dissipation	$T_A = 25^\circ\text{C}$	$P_D$	2.1	W
	$T_A = 70^\circ\text{C}$		1.4	
Operating Junction & Storage Temperature Range		$T_j, T_{stg}$	-55 to 150	°C

**THERMAL RESISTANCE RATINGS**

THERMAL RESISTANCE	SYMBOL	TYPICAL	MAXIMUM	UNITS
Junction-to-Ambient <sup>2</sup>	$R_{\theta JA}$		57	°C / W
Junction-to-Case	$R_{\theta JC}$		4	

<sup>1</sup>Pulse width limited by maximum junction temperature.<sup>2</sup>The value of  $R_{\theta JA}$  is measured with the device mounted on 1in<sup>2</sup> FR-4 board with 2oz. Copper, in a still air environment with  $T_A = 25^\circ\text{C}$ .**ELECTRICAL CHARACTERISTICS ( $T_J = 25^\circ\text{C}$ , Unless Otherwise Noted)**

PARAMETER	SYMBOL	TEST CONDITIONS	LIMITS			UNIT
			MIN	TYP	MAX	
<b>STATIC</b>						
Drain-Source Breakdown Voltage	$V_{(BR)DSS}$	$V_{GS} = 0\text{V}, I_D = 250\mu\text{A}$	30			V
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D = 250\mu\text{A}$	1.3	1.5	3	

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Gate-Body Leakage	$I_{GSS}$	$V_{DS} = 0V, V_{GS} = \pm 20V$			$\pm 100$	nA
Zero Gate Voltage Drain Current	$I_{DSS}$	$V_{DS} = 24V, V_{GS} = 0V$			1	$\mu A$
		$V_{DS} = 20V, V_{GS} = 0V, T_J = 55^\circ C$			10	
Drain-Source On-State Resistance <sup>1</sup>	$R_{DS(ON)}$	$V_{GS} = 4.5V, I_D = 15A$		9.4	12	$m\Omega$
		$V_{GS} = 10V, I_D = 20A$		6.8	9	
Forward Transconductance <sup>1</sup>	$g_{fs}$	$V_{DS} = 5V, I_D = 20A$		60		S
<b>DYNAMIC</b>						
Input Capacitance	$C_{iss}$	$V_{GS} = 0V, V_{DS} = 15V, f = 1MHz$		638		$pF$
Output Capacitance	$C_{oss}$			130		
Reverse Transfer Capacitance	$C_{rss}$			77		
Gate Resistance	$R_g$	$V_{GS} = 0V, V_{DS} = 0V, f = 1MHz$		2.5		$\Omega$
Total Gate Charge <sup>2</sup>	$Q_g$	$V_{DS} = 15V, V_{GS} = 10V, I_D = 20A$		14.5		$nC$
				8		
Gate-Source Charge <sup>2</sup>	$Q_{gs}$			2		
Gate-Drain Charge <sup>2</sup>	$Q_{gd}$			4		
Turn-On Delay Time <sup>2</sup>	$t_{d(on)}$	$V_{DS} = 15V, I_D \approx 20A, V_{GS} = 10V, R_{GEN} = 6\Omega$		18		$nS$
Rise Time <sup>2</sup>	$t_r$			15		
Turn-Off Delay Time <sup>2</sup>	$t_{d(off)}$			34		
Fall Time <sup>2</sup>	$t_f$			16		
<b>SOURCE-DRAIN DIODE RATINGS AND CHARACTERISTICS (<math>T_J = 25^\circ C</math>)</b>						
Continuous Current	$I_S$				43	A
Forward Voltage <sup>1</sup>	$V_{SD}$	$I_F = 20A, V_{GS} = 0V$			1.2	V
Reverse Recovery Time	$t_{rr}$	$I_F = 20A, dI_F/dt = 100A/\mu S$		14		$nS$
Reverse Recovery Charge	$Q_{rr}$			5		$nC$

<sup>1</sup>Pulse test : Pulse Width  $\leq 300 \mu sec$ , Duty Cycle  $\leq 2\%$ .

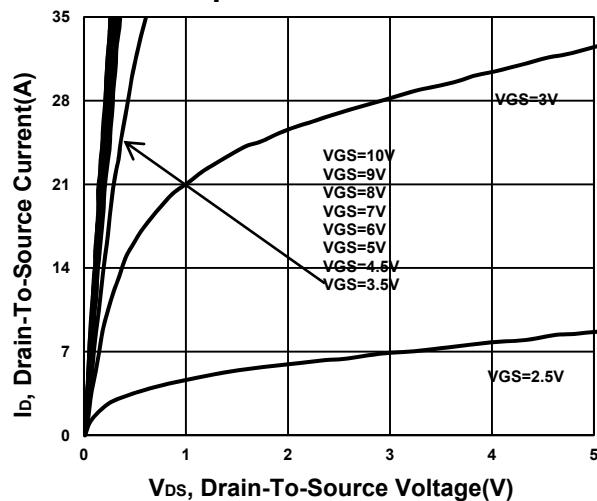
<sup>2</sup>Independent of operating temperature.

**NIKO-SEM**

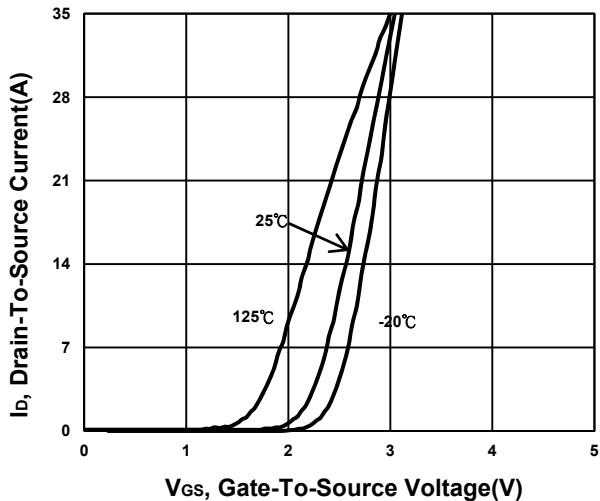
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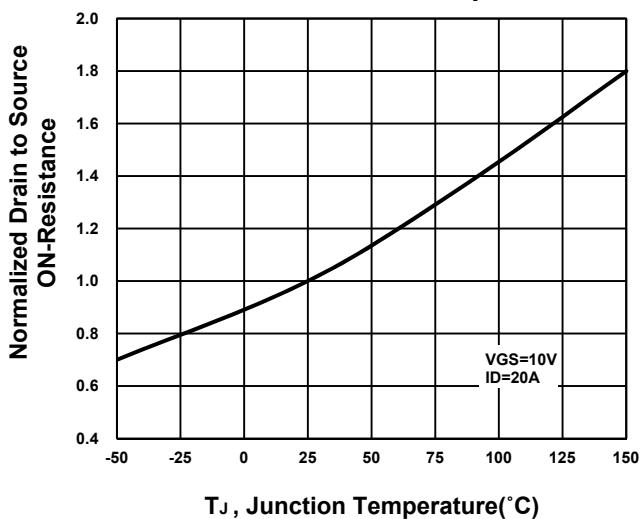
### Output Characteristics



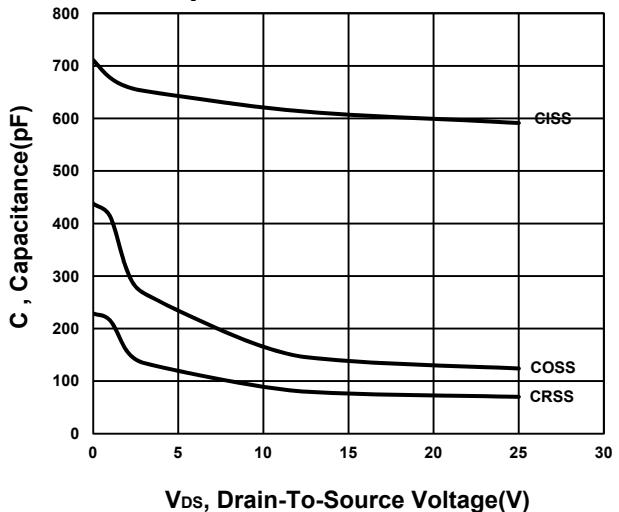
### Transfer Characteristics



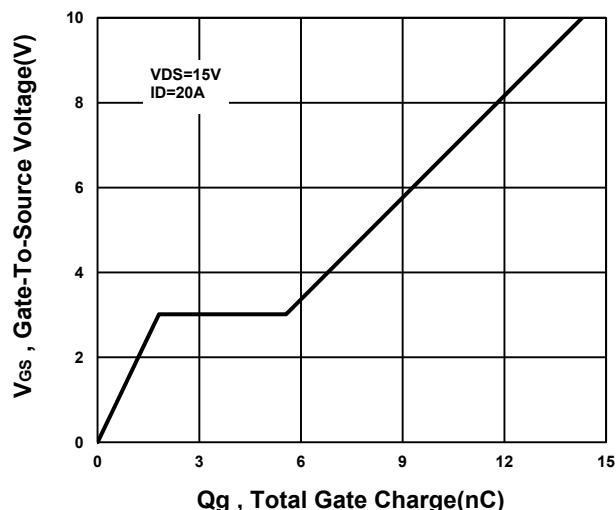
### On-Resistance VS Temperature



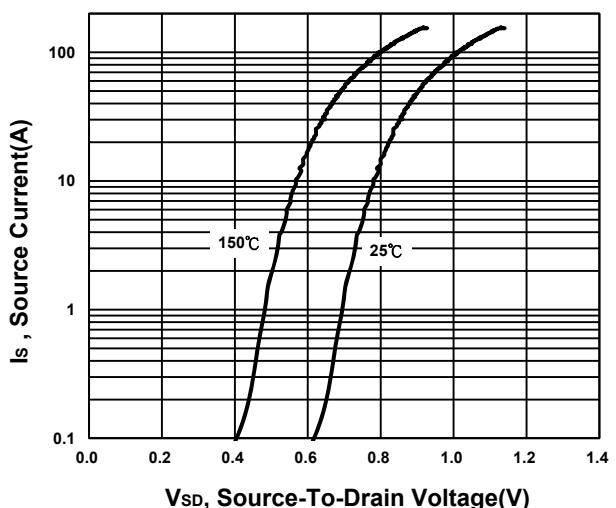
### Capacitance Characteristic



### Gate charge Characteristics



### Source-Drain Diode Forward Voltage

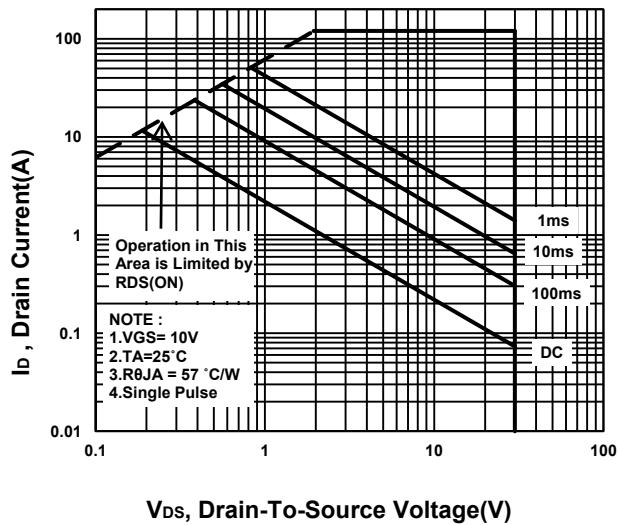


**NIKO-SEM**

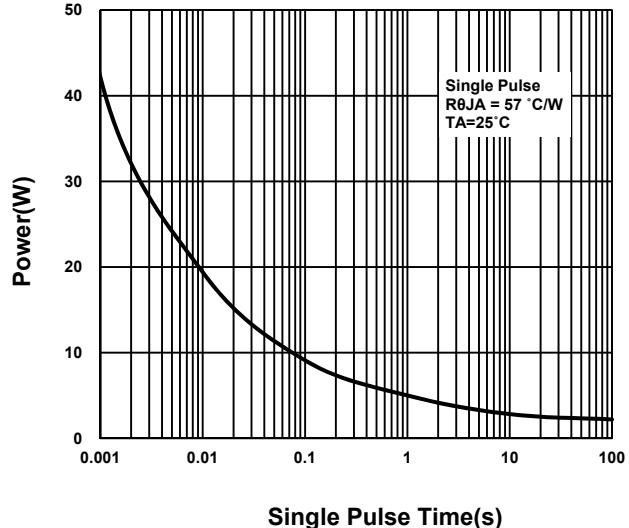
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### Safe Operating Area



### Single Pulse Maximum Power Dissipation



### Transient Thermal Response Curve

